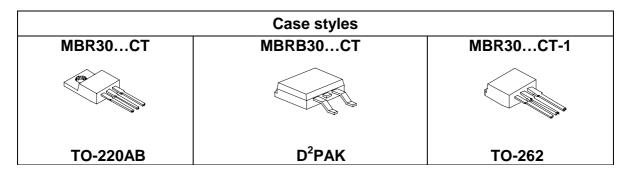
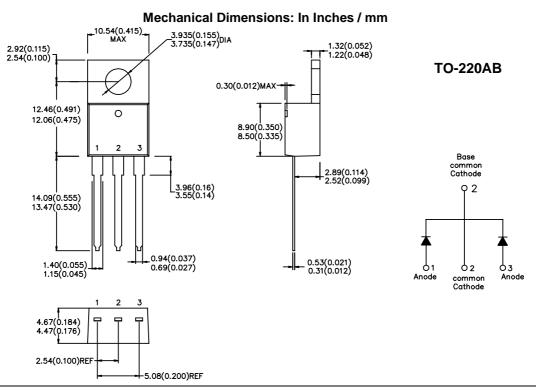
Technical Data Data Sheet 2916, Rev.C

MBR30...CT/MBRB30...CT/MBR30...CT-1 SCHOTTKY RECTIFIER

Applications:

- Switching power supply Converters Free-Wheeling diodes Reverse battery protection Features:
 - 150 °C T_J operation
 - Center tap configuration
 - Low forward voltage drop
 - High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
 - High frequency operation
 - · Guard ring for enhanced ruggedness and long term reliability

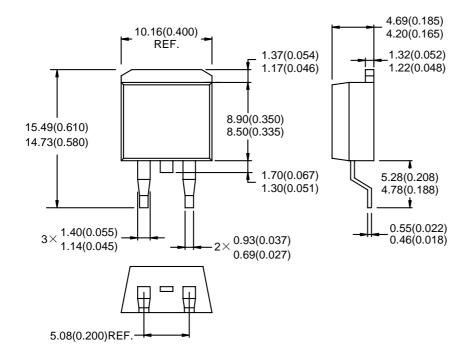


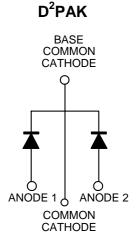


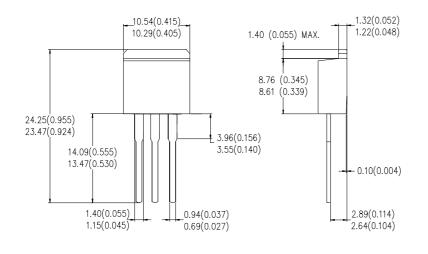
- 221 West Industry Court ☐ Deer Park, NY 11729-4681 ☐ (631) 586-7600 FAX (631) 242-9798
 - World Wide Web Site http://www.sensitron.com E-Mail Address sales@sensitron.com •

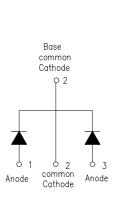
SENSITRON SEMICONDUCTOR

Data Sheet 2916, Rev. C

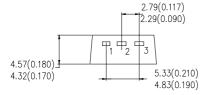








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SENSITRON SEMICONDUCTOR

Data Sheet 2916, Rev. C Maximum Ratings:

Characteristics	Symbol	Condition		Max.	Units
Peak Inverse Voltage	V_{RWM}	-	35	MBR3035CT MBRB3035CT MBR3035CT-1	
			45	MBR3045CT MBRB3045CT MBR3045CT-1	V
Max. Average Forward	I _{F(AV)}	50% duty cycle @T _C = 123°C, rectangular wave form	3	15(Per leg) 80(Per Device)	Α
Max. Peak One Cycle Non- Repetitive Surge Current	I _{FSM}	8.3 ms, half Sine pulse		240	А

Electrical Characteristics:

Characteristics	Symbol	Condition	Max.	Units
Max. Forward Voltage Drop (per leg) *	V_{F1}	@ 30A, Pulse, T _J = 25 °C	0.84	V
	V_{F2}	 @ 15A, Pulse, T_J = 125 °C @ 30A, Pulse, T_J = 125 °C 	0.57 0.72	V
Max. Reverse Current (per leg) *	I _{R1}	$@V_R = \text{rated } V_R$ $T_J = 25 ^{\circ}\text{C}$	1.0	mA
	I _{R2}	$@V_R = \text{rated } V_R$ $T_J = 100 ^{\circ}\text{C}$	40	mA
Max. Junction Capacitance (per leg)	C _T	$@V_R = 4V, T_C = 25 ^{\circ}C$ $f_{SIG} = 1MHz$	500	pF
Typical Series Inductance (per leg)	L _S	Measured lead to lead 5 mm from package body	8.0	nH
Max. Voltage Rate of Change	dv/dt	-	10,000	V/μs

^{*} Pulse Width < 300µs, Duty Cycle <2%

Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification	Units	
Max. Junction Temperature	T_J	-	-55 to +150	°C	
Max. Storage Temperature	T_{stg}	-	-55 to +150	°C	
Maximum Thermal Resistance Junction to Case	R _{θJC}	DC operation	1.6	°C/W	
Maximum Thermal Resistance, Case to Heat Sink	$R_{\theta JA}$	DC operation	50	°C/W	
Approximate Weight	wt	-	2	g	
Mounting Torque	T _M	-	6(Min.) 12(Max.)	Kg-cm	
Case Style	TO-220AB D ² PAK TO-262				

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SENSITRON SEMICONDUCTOR

MBR3035/3045CT MBRB3035/3045CT MBR3035/3045CT-1

Technical Data Data Sheet 2916, Rev. C

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